TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC2703

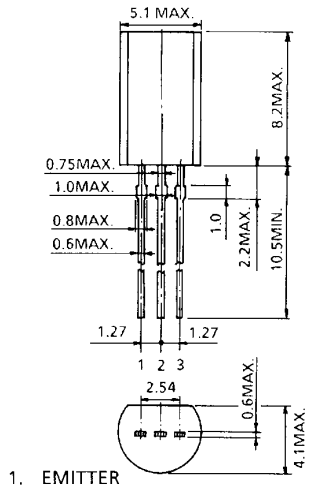
Audio Power Amplifier Applications

- High DC current gain: h_{FE} = 100 to 320

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	30	V
Collector-emitter voltage	V_{CEO}	30	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	1	A
Base current	I_B	0.1	A
Collector power dissipation	P_C	900	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	−55 to 150	°C

Unit: mm



JEDEC	TO-92MOD
JEITA	—
TOSHIBA	2-5J1A

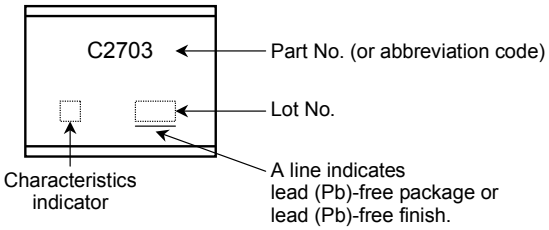
Weight: 0.36 g (typ.)

Electrical Characteristics (Ta = 25°C)

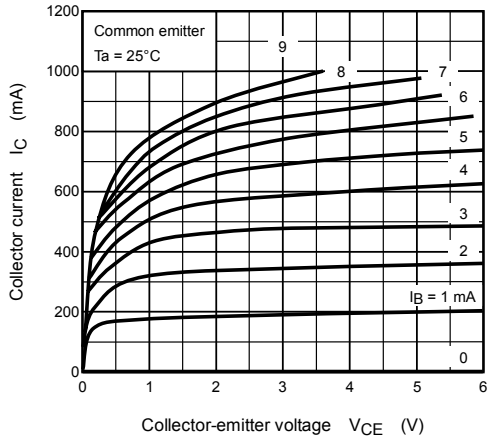
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	V_{CB} = 30 V, I_E = 0	—	—	100	nA
Emitter cut-off current	I_{EBO}	V_{EB} = 5 V, I_C = 0	—	—	100	nA
Collector-emitter breakdown voltage	$V_{(BR)\ CEO}$	I_C = 10 mA	30	—	—	V
DC current gain	$h_{FE\ (1)}$ (Note)	V_{CE} = 2 V, I_C = 100 mA	100	—	320	
	$h_{FE\ (2)}$	V_{CE} = 2 V, I_C = 800 mA	40	—	—	
Collector-emitter saturation voltage	$V_{CE\ (sat)}$	I_C = 800 mA, I_B = 80 mA	—	—	0.5	V
Base-emitter voltage	V_{BE}	V_{CE} = 2 V, I_C = 800 mA	—	0.9	1.5	V
Transition frequency	f_T	V_{CE} = 2 V, I_C = 100 mA	—	150	—	MHz
Collector output capacitance	C_{ob}	V_{CB} = 10 V, f = 1 MHz	—	13	—	pF

Note: $h_{FE\ (1)}$ classification O: 100 to 200, Y: 160 to 320

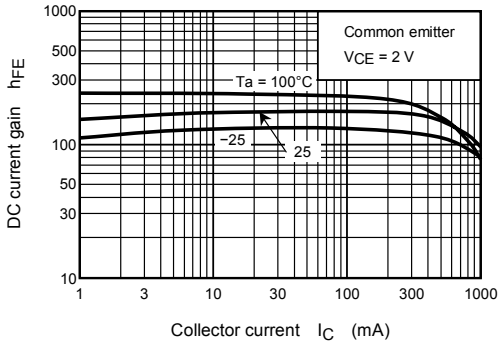
Marking


C2703
Part No. (or abbreviation code)
Lot No.
A line indicates
lead (Pb)-free package or
lead (Pb)-free finish.
Characteristics
indicator

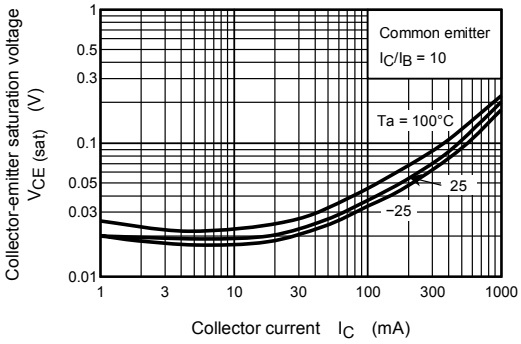
$I_C - V_{CE}$



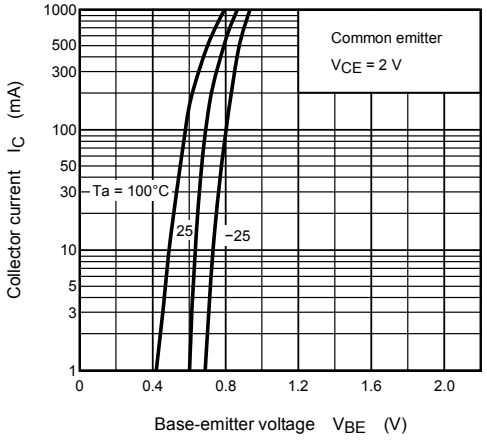
$h_{FE} - I_C$



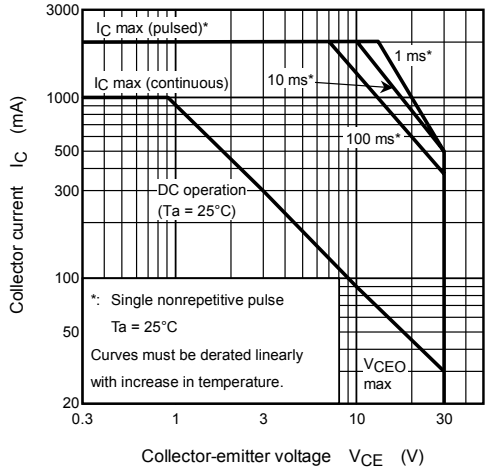
$V_{CE\ (sat)} - I_C$



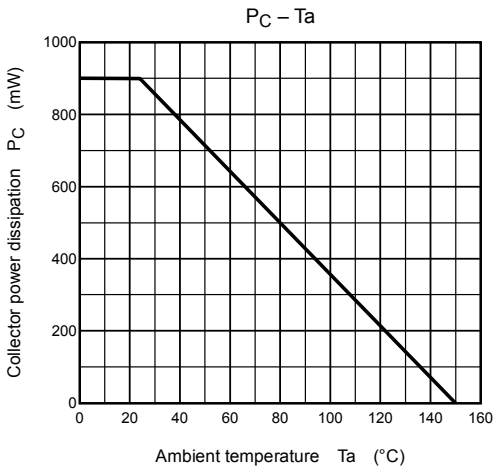
$I_C - V_{BE}$



Safe Operating Area



$P_C - Ta$



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